



# N-Channel 60-V (D-S) Fast Switching MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
60	$0.0083$ at $V_{GS} = 10 \text{ V}$	19.3	105		

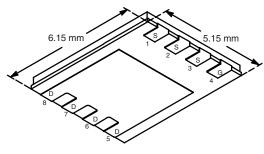
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile
- 100 % R<sub>g</sub> Tested
- High Threshold Voltage At High Temperature





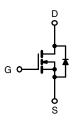
#### PowerPAK SO-8



**Bottom View** 

Ordering Information: Si7452DP-T1-E3 (Lead (Pb)-free)

Si7452DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS TA	$_{c}$ = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	60		V
Gate-Source Voltage		$V_{GS}$	± 20		
Continuous Drain Current (T <sub>1</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	19.3	11.5	
Continuous Diairi Current (1) = 150 °C)	T <sub>A</sub> = 70 °C		15.5	9.2	
Pulsed Drain Current		I <sub>DM</sub>	60		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	4.5	1.6	
Avalanche Current		I <sub>AS</sub>	40		
Avalanche Energy		E <sub>AS</sub>	80		mJ
Manipular Danier Dissipation 8	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5.4	1.9	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		3.4	1.2	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) <sup>b,c</sup>			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 s	R <sub>thJA</sub>	18	23	°C/W	
Maximum Junction-to-Ambient	Steady State		52	65		
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	1.0	1.3		

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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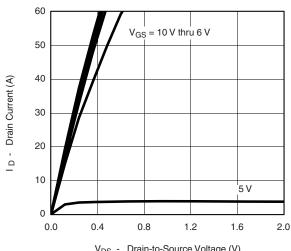
Parameter Symbol		Test Condition	Min.	Тур.	Max.	Unit	
Static				•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.4		4.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
7 0	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V	V, V <sub>GS</sub> = 0 V		1	μΑ	
Zero Gate Voltage Drain Current		V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			5		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 19.3 A		0.007	0.0083	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 19.3 \text{ A}$		51		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V	
Dynamic <sup>b</sup>	<u> </u>						
Total Gate Charge	Qg			105	160	nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 19.3 \text{ A}$		40			
Gate-Drain Charge	$Q_{gd}$			21			
Gate Resistance	$R_g$	f = 1 MHz	0.5	1.0	1.5	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			45	70		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 30 $\Omega$		15	25		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		90	135	ns	
Fall Time	t <sub>f</sub>			40	60	110	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 4.5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		46	70		

#### Notes:

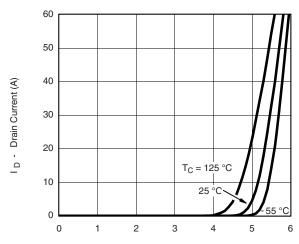
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



V<sub>DS</sub> - Drain-to-Source Voltage (V) **Output Characteristics** 



V<sub>GS</sub> - Gate-to-Source Voltage (V)

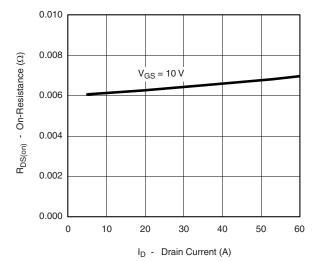
**Transfer Characteristics** 



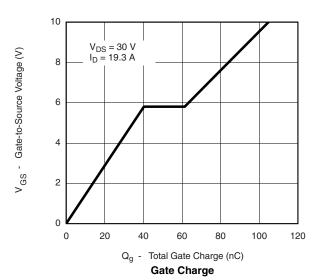


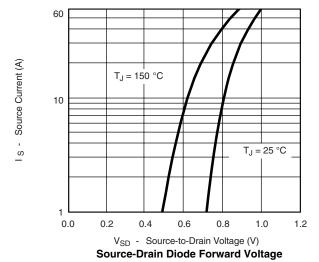


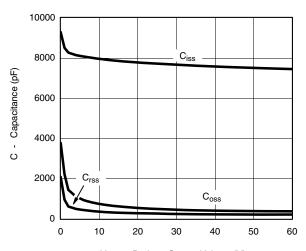
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



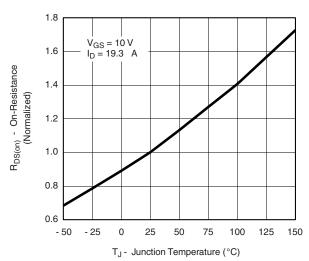
#### **On-Resistance vs. Drain Current**



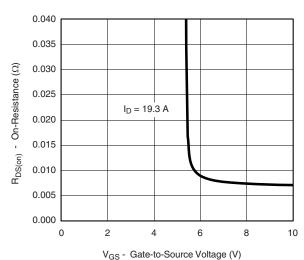




V<sub>DS</sub> - Drain-to-Source Voltage (V) **Capacitance** 



On-Resistance vs. Junction Temperature

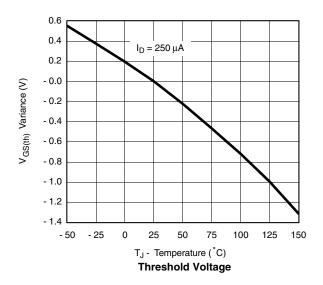


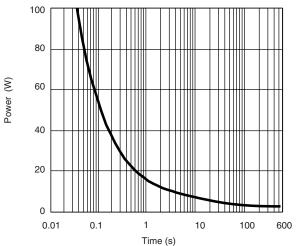
On-Resistance vs. Gate-to-Source Voltage

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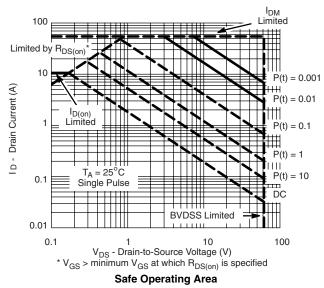
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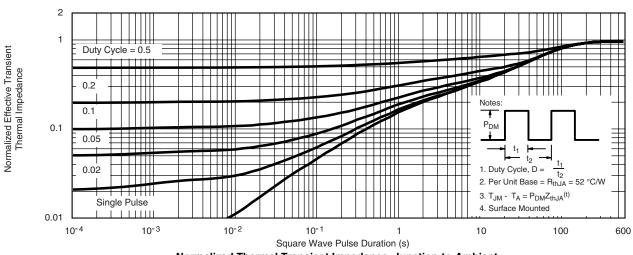
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Single Pulse Power, Junction-to-Ambient

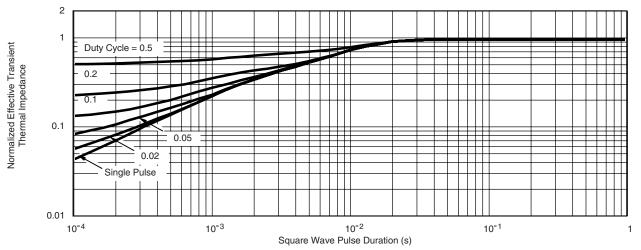




Normalized Thermal Transient Impedance, Junction-to-Ambient



### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?72972">www.vishay.com/ppg?72972</a>.

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